

L-7083PWW-H

WHITE

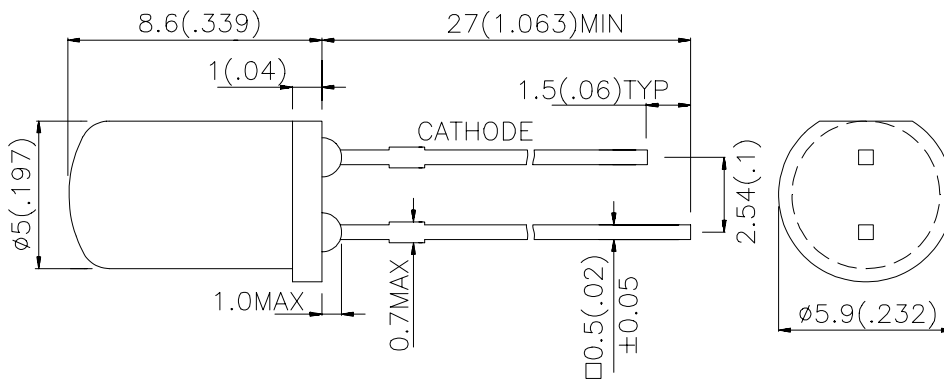
Features

- OUTSTANDING MATERIAL EFFICIENCY.
- RELIABLE AND RUGGED.
- I.C. COMPATIBLE.

Description

The source color devices are made with InGaN on SiC Light Emitting Diode.

Package Dimensions



Notes:

1. All dimensions are in millimeters (inches).
2. Tolerance is $\pm 0.25(0.01)$ unless otherwise noted.
3. Lead spacing is measured where the lead emerge package.
4. Specifications are subject to change without notice.

Selection Guide

Part No.	Dice	Lens Type	Iv (mcd) @ 20 mA		Viewing Angle
			Min.	Typ.	θ1/2
L-7083PWW-H	WHITE (InGaN)	WHITE DIFFUSED	480	1000	60°

Note:

1. θ1/2 is the angle from optical centerline where the luminous intensity is 1/2 the optical centerline value.

Electrical / Optical Characteristics at T_A=25°C

Symbol	Parameter	Device	Typ.	Max.	Units	Test Conditions
V _F	Forward Voltage	White	3.7	4.3	V	I _F =20mA
I _R	Reverse Current	White		10	μA	V _R = 5V
X	Chromaticity Coordinates	White	0.33			
Y			0.34			
C	Capacitance	White	110		pF	V _F =0V, f =1MHz

Absolute Maximum Ratings at T_A=25°C

Parameter	White	Units
Power dissipation	108	mW
DC Forward Current	30	mA
Peak Forward Current [1]	100	mA
Reverse Voltage	5	V
Operating/Storage Temperature	-40°C To +85°C	
Lead Solder Temperature [2]	260°C For 5 Seconds	

Notes:

- 1/10 Duty Cycle, 0.1ms Pulse Width.
- 2mm below package base.

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